| | Application No. | Applicant(s) |
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| Notice of Allowability | 09/973,814 | KUNIYASU ET AL. |
| | Examiner | Art Unit |
| | Tuan N Nguyen | 2828 |
| The MAILING DATE of this communication apperation apperation all claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI of the Office or upon petition by the applicant. See 37 CFR 1.313 | ears on the cover sheet wi (OR REMAINS) CLOSED in or other appropriate commit GHTS. This application is s | n this application. If not included unication will be mailed in due course. THIS |
| · | | |
| 2. The allowed claim(s) is/are <u>1-9 and 12-18</u> . | | |
| 3. The drawings filed on 11 October 2001 are accepted by the | e Examiner. | |
| 4. Acknowledgment is made of a claim for foreign priority una) All b) Some* c) None of the: Certified copies of the priority documents have Certified copies of the priority documents have Copies of the certified copies of the priority documents have Topies of the certified copies of the priority documents have Copies of the certified copies of the priority documents have Copies of the certified copies of the priority documents have Copies of the certified copies of the priority documents have Copies of the certified copies of the priority documents have Topies of the certified copies of the priority documents have Applicant has THREE MONTHS FROM THE "MAILING DATE" | been received. been received in Application | on No If in this national stage application from the |
| noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE. 5. A SUBSTITUTE OATH OR DECLARATION must be submit | ENT of this application. Itted. Note the attached EXA | AMINER'S AMENDMENT or NOTICE OF |
| INFORMAL PATENT APPLICATION (PTO-152) which give | , , , | declaration is deficient. |
| 6. ☐ CORRECTED DRAWINGS (as "replacement sheets") must be submitted. (a) ☐ including changes required by the Notice of Draftsperson's Patent Drawing Review (PTO-948) attached | | |
| 1) ☐ hereto or 2) ☐ to Paper No./Mail Date | | |
| (b) ☐ including changes required by the attached Examiner's Paper No./Mail Date | | in the Office action of |
| Identifying indicia such as the application number (see 37 CFR 1. each sheet. Replacement sheet(s) should be labeled as such in the | | |
| 7. DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT R | | |
| Attachment(s) 1. Notice of References Cited (PTO-892) 2. Notice of Draftperson's Patent Drawing Review (PTO-948) 3. Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date 4. Examiner's Comment Regarding Requirement for Deposit of Biological Material | 6. ⊠ Interview Si Paper No./ 8), 7. □ Examiner's | formal Patent Application (PTO-152) ummary (PTO-413), Mail Date <u>12/17/04</u> . Amendment/Comment Statement of Reasons for Allowance |
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DETAIL ACTION

Response to Amendment

1. In responding to applicant's amendment filed 11/12/2004, claims 1, 12, and 17 have been amended, claims 10, 11 have been canceled, and claims 18 have been added.

REASON FOR ALLOWANCE

Allowable Subject Matter

2. The following is an examiner's statement of reasons for allowance - Applicant's response filed on 11/12/2004 has been considered, with respect to claims 1, 12, 17 and 18 the references of the record fail to teach or suggest:

Claims 1, 17:

A solid-state laser having a stack layer, with two exposed portions with depth exposed continuous from two resonator end faces, and a ridge has current injection window formed in a top surface of said ridge portion, between two exposed portions, where in a portion of a contact layer near the resonator end face is removed; and an insulating film covered the region, excluding current injection window, having an electrode exposed to the current injection window.

Claims 12, 18:

A semiconductor device having two resonator end faces with cladding layer, optical waveguide, active layer, barrier layer, and substrate, having thickness differences between barrier layers (10-30nm), product of tensile strain and thickness of the barriers is between

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0.05nm to 0.2nm, with quantum well having tensile strain of ~0.007 with respect to GaAs

substrate, and a current non-injection region is near opposite resonator end face of contact layer.

3. Any comments considered necessary by applicant must be submitted no later than the

payment of the issue fee and, to avoid processing delays, should preferably accompany the issue

fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for

Allowance."

Communication Information

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Tuan N Nguyen whose telephone number is (571) 272-1948. The

examiner can normally be reached on M-F.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Harvey Minsun can be reached on (703) 308-16741. The fax phone number for the

organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent

Application Information Retrieval (PAIR) system. Status information for published applications

may be obtained from either Private PAIR or Public PAIR. Status information for unpublished

applications is available through Private PAIR only. For more information about the PAIR

system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR

system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Tuan N. Nguyen

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